NSN 5962-01-272-4450

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View Online at https://aerobasegroup.com/nsn/5962-01-272-4450
Body Length:
1.490 inches
Body Width:
0.610 inches
Body Height:
0.217 inches
Maximum Power Dissipation Rating:
1.0 watts
Operating Tempurature Range:
-55.0/+125.0 degrees celsius
Storage Tempurature Range:
-65.0/+150.0 degrees celsius
Features Provided:
Monolithic and ultraviolet erasable and programmable
Inclosure Material:
Ceramic
Inclosure Configuration:
Dual-in-line
Output Logic Form:
Metal oxide-semiconductor logic
Input Circuit Pattern:
23 input
Case Outline Source And Designator:
D-10 mil-m-38510
Current Rating Per Characteristic:
125.00 milliamperes reverse current, dc absolute
Terminal Surface Treatment:
Solder
Voltage Rating And Type Per Characteristic:
6.2 volts power source
Time Rating Per Chacteristic:
200.00 nanoseconds access
Memory Device Type:
Eprom
Test Data Document:
81349-mil-m-38510 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification
format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain
environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.).
Terminal Type And Quantity:
28 printed circuit
Specification Data:

N/a

Shelf Life:

81349-mil-m-38510/224 government specification

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Demilitarization:

Yes - demil/mli

Fiig:

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